## NSN 5962-01-040-4352

Memory Microcircuit - Page 1 of 2



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Between 0.750 inches and 0.795 inches

**Body Width:** 

Between 0.245 inches and 0.300 inches

**Body Height:** 

Between 0.120 inches and 0.195 inches

**Maximum Power Dissipation Rating:** 

625.0 milliwatts

## **Operating Tempurature Range:**

+0.0/+75.0 degrees celsius

## **Storage Tempurature Range:**

-65.0/+150.0 degrees celsius

#### **End Application:**

Cheyenne aircraft model 427m

## **Features Provided:**

Bipolar and hermetically sealed and high speed and monolithic and positive outputs and programmable and programmed and w/buffered output and w/decoded output and w/disable and w/enable and w/storage and 3-state output

#### **Inclosure Material:**

Ceramic and glass

## **Inclosure Configuration:**

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## **Input Circuit Pattern:**

10 input

## **Case Outline Source And Designator:**

-0-001-ag joint electron device engineering council

## **Terminal Surface Treatment:**

Solder

## **Voltage Rating And Type Per Characteristic:**

-1.5 volts power source and 5.5 volts power source

## **Time Rating Per Chacteristic:**

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

## **Memory Device Type:**

Rom

## **Test Data Document:**

11530-278539 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

16 printed circuit

## Shelf Life:

N/a

## **Unit Of Measure:**

# NSN 5962-01-040-4352

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

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